

Triac Medium Power Use

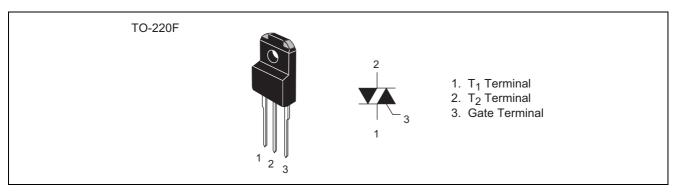
> REJ03G0302-0200 Rev.2.00 Nov.08.2004

Features

- $I_{T(RMS)}: 5 A$
- V_{DRM} : 600 V
- I_{FGTI} , I_{RGTI} , I_{RGT} : 20 mA (10 mA)^{Note5}
- Viso : 2000 V

Outline

- Insulated Type
- Planar Passivation Type
 - UL Recognized : Yellow Card No. E223904 File No. E80271



Applications

Switching mode power supply, light dimmer, electronic flasher unit, control of household equipment such as TV sets, stereo systems, refrigerator, washing machine, infrared kotatsu, carpet, and solenoid driver, small motor control, copying machine, electric tool, electric heater control, and other general controlling device

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	
Falameter	Symbol	12		
Repetitive peak off-state voltage ^{Note1}	V _{DRM}	600	V	
Non-repetitive peak off-state voltage ^{Note1}	V _{DSM}	720	V	

BCR5PM-12L

Parameter	Symbol	Ratings	Unit	Conditions	
RMS on-state current	I _{T (RMS)}	5	A	Commercial frequency, sine full way 360° conduction, Tc = 95°C	
Surge on-state current	I _{TSM}	50	A	60Hz sinewave 1 full cycle, peak value, non-repetitive	
I ² t for fusing	l ² t	10.4	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	
Peak gate power dissipation	P _{GM}	3	W		
Average gate power dissipation	P _{G (AV)}	0.3	W		
Peak gate voltage	V _{GM}	10	V		
Peak gate current	I _{GM}	2	А		
Junction temperature	Tj	- 40 to +125	°C		
Storage temperature	Tstg	- 40 to +125	°C		
Mass	—	2.0	g	Typical value	
Isolation voltage	Viso	2000	V	Ta = 25°C, AC 1 minute, T ₁ ·T ₂ ·G terminal to case	

Notes: 1. Gate open.

Electrical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cur	rent	I _{DRM}	—	—	2.0	mA	Tj = 125°C, V _{DRM} applied
On-state voltage		V _{TM}	_	—	1.8	V	$Tc = 25^{\circ}C$, $I_{TM} = 7 A$, Instantaneous measurement
Gate trigger voltage ^{Note2}	Ι	V _{FGTI}	_	—	1.5	V	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	V _{RGTI}	—	—	1.5	V	$R_G = 330 \Omega$
	III	V _{RGTIII}	—	—	1.5	V	
Gate trigger current ^{Note2}	Ι	I _{FGTI}	_	—	20 ^{Note5}	mA	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	I _{RGTI}	—	—	20 ^{Note5}	mA	$R_G = 330 \Omega$
	III	I _{RGTIII}	_	—	20 ^{Note5}	mA	
Gate non-trigger voltage		V_{GD}	0.2	—	—	V	$Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$
Thermal resistance		R _{th (j-c)}	_	—	4.0	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-stat commutating voltage ^{Note4}	е	(dv/dt)c	5	—	—	V/µs	Tj = 125°C

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

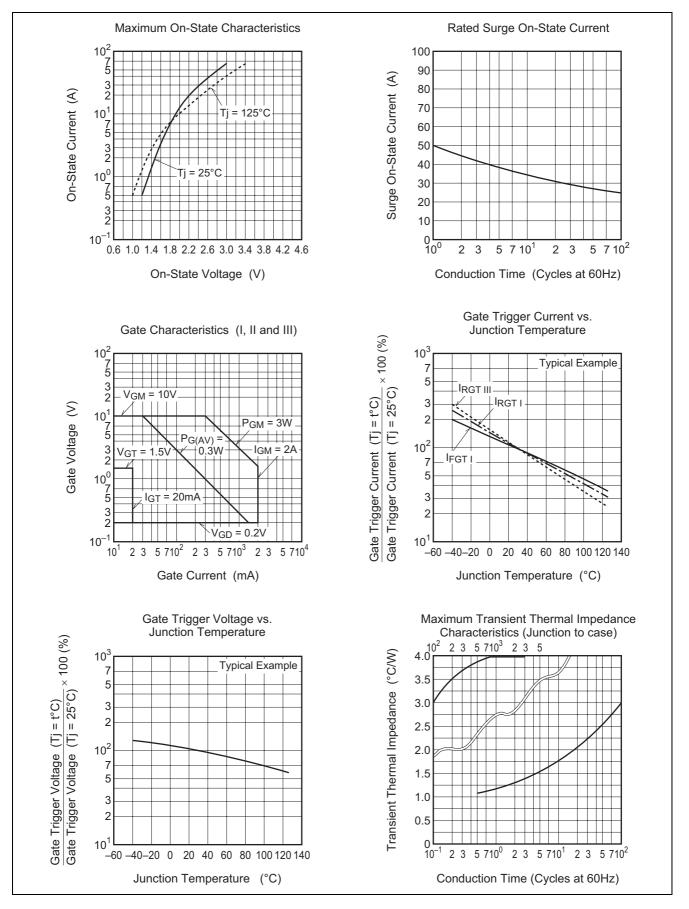
3. The contact thermal resistance $R_{th\,(c\text{-}f)}$ in case of greasing is 0.5°C/W.

4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

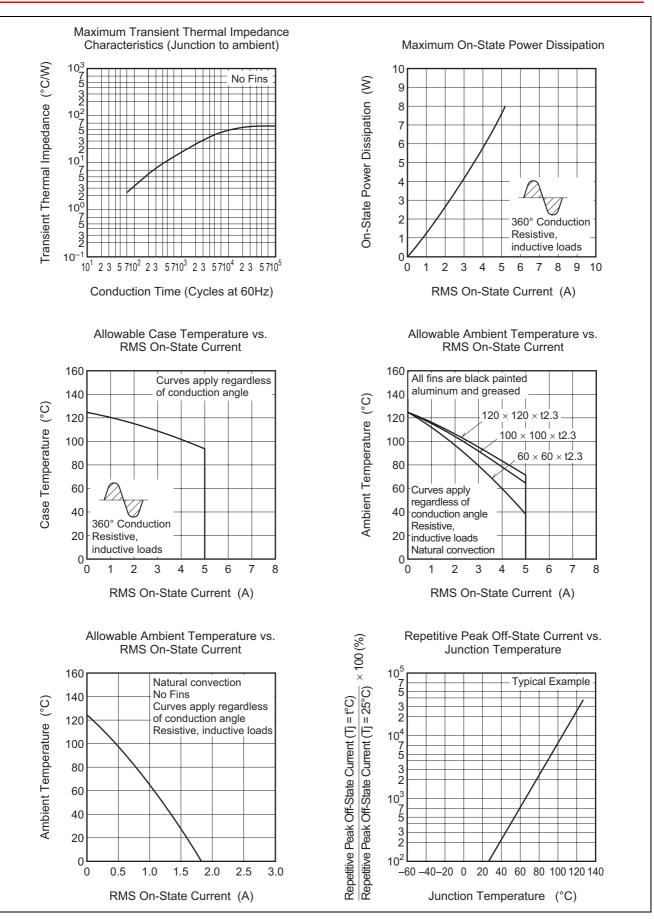
5. High sensitivity (I_{GT} \leq 10 mA) is also available. (I_{GT} item: 1)

Test conditions	Commutating voltage and current waveforms (inductive load)				
1. Junction temperature Tj = 125°C	Supply Voltage → Time				
 Rate of decay of on-state commutating current (di/dt)c = - 2.5 A/ms 	Main Current → Time				
3. Peak off-state voltage $V_D = 400 \text{ V}$	Main VoltageTime (dv/dt)cV				

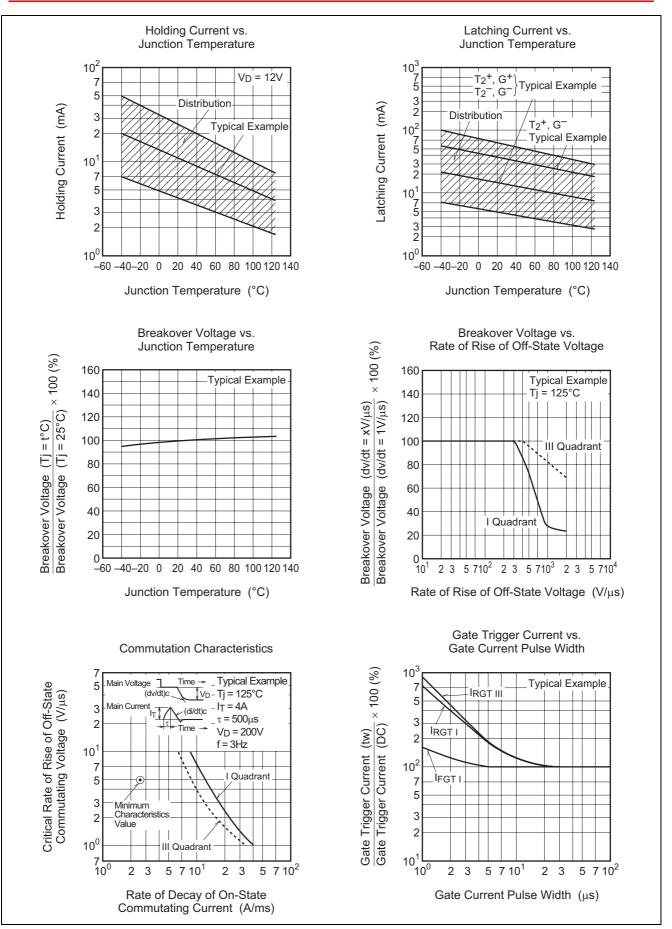
Performance Curves

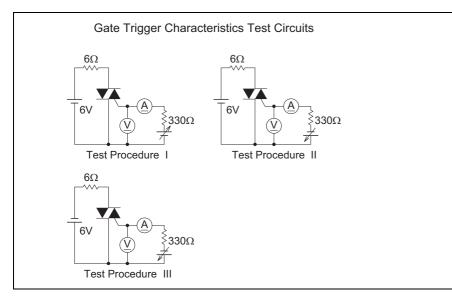




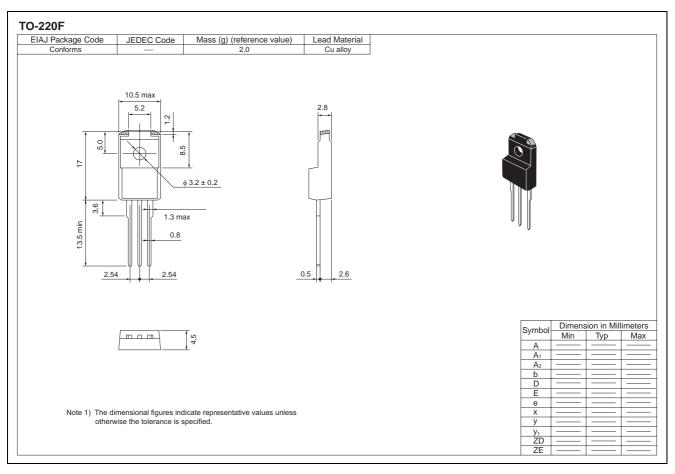








Package Dimensions



Order Code

Standard packing	Quantity	Standard order code	Standard order code example
Vinyl sack	100	Type name +A	BCR5PM-12LA
Plastic Magazine (Tube)	50	Type name +A – Lead forming code	BCR5PM-12LA-A8
	Vinyl sack	Vinyl sack 100	Vinyl sack 100 Type name +A

Note : Please confirm the specification about the shipping in detail.

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